TOSHIBA Photocoupler Photorelay

TLP172G

Modem Fax Cards, Modems in PC

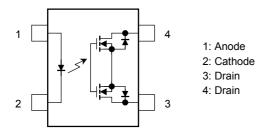
Telecommunications PBX Measurement Equipment

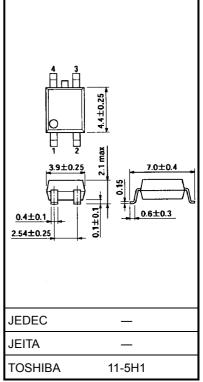
The Toshiba TLP172G consists of an aluminum gallium arsenide infrared emitting diode optically coupled to a photo-MOSFET in a SOP, which is suitable for surface mount assembly.

The TLP172G is suitable for the modem applications which require space savings.

- 4-pin SOP (2.54SOP4): Height = 2.1 mm, Pitch = 2.54 mm
- 1-Form-A
- Peak Off-state voltage: 350 V (min)
- Trigger LED current: 3 mA (max)
- On-state current: 110 mA (max)
- On-state resistance: $35 \Omega (\max t < 1 s)$
- On-state resistance: 50 Ω (max continuous)
- Isolation voltage: 1500 Vrms (min)

Pin Configuration (top view)





Weight: 0.1 g (typ.)

Unit: mm

Maximum Rating (Ta = 25°C)

	Characteristics	Symbol	Rating	Unit
	Forward current	١ _F	50	mA
LED	Forward current derating (Ta ≧ 25°C)	∆I _F /°C	-0.5	mA/°C
	Reverse voltage	V _R	5	V
	Junction temperature	Tj	125	°C
Detector	Off-state output terminal voltage	V _{OFF}	350	V
	On-state current	I _{ON}	110	mA
	On-state current derating (Ta ≧ 25°C)	∆l _{ON} /°C	-1.1	mA/°C
	Junction temperature	Tj	125	°C
Storage temperature range		T _{stg}	-55~125	°C
Operating temperature range		T _{opr}	-40~85	°C
Lead soldering temperature (10 s)		T _{sol}	260	°C
Isolation voltage (AC, 1 min, R.H. \leq 60%) (Note 1)		BVS	1500	Vrms

Note 1: Device considered a two-terminal device: LED side pins shorted together, and detector side pins shorted together.

Recommended Operating Conditions

Characteristics	Symbol	Min	Тур.	Max	Unit
Supply voltage	V _{DD}		_	280	V
Forward current	١ _F	5	7.5	25	mA
On-state current	I _{ON}	_	_	100	mA
Operating temperature	T _{opr}	-20	_	65	°C

Electrical Characteristics (Ta = 25°C)

	Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
	Forward voltage	V _F	I _F = 10 mA	1.0	1.15	1.3	V
LED	Reverse current	Ι _R	$V_R = 5 V$	_	_	10	μA
	Capacitance	CT	V = 0, f = 1 MHz	_	30	_	pF
Detector	Off-state current	I _{OFF}	V _{OFF} = 350 V	_	_	1	μA
Delector	Capacitance	COFF	V = 0, f = 1 MHz	_	30	_	pF

Coupled Electrical Characteristics (Ta = 25°C)

Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Trigger LED current	I _{FT}	I _{ON} = 110 mA	_	1	3	mA
Return LED current	I _{FC}	I _{OFF} = 100 μA	0.1	_	_	mA
On-state resistance	R _{ON}	I _{ON} = 110 mA, I _F = 5 mA, t < 1 s	_	25	35	Ω
	1 ON	$I_{ON} = 110$ mA, $I_{F} = 5$ mA, continuous	_	35	50	52

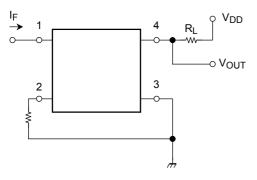
Isolation Characteristics (Ta = 25°C)

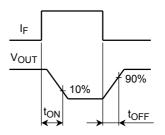
Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Capacitance input to output	CS	$V_{S} = 0 V, f = 1 MHz$		0.8	_	pF
Isolation resistance	R _S	$V_{S} = 500 \text{ V}, \text{ R.H.} \le 60\%$	5×10^{10}	10 ¹⁴	_	Ω
	AC, 1 min BV _S AC, 1 s, in	AC, 1 min	1500	_	_	Vrms
Isolation voltage		AC, 1 s, in oil		3000	_	VIIIIS
		DC, 1 min, in oil	—	3000	_	Vdc

Switching Characteristics (Ta = 25°C)

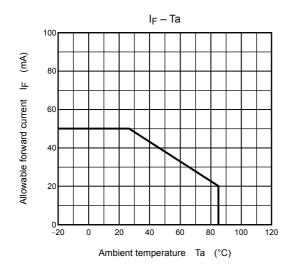
Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Turn-on time t_{ON} $R_L = 200 \Omega$		_	0.3	1	ms	
Turn-off time	t _{OFF}	$V_{DD} = 20 \text{ V}, \text{ I}_{\text{F}} = 5 \text{ mA}$ (Note 2)		0.1	1	1113

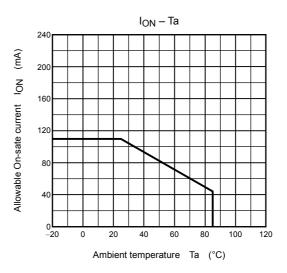
Note 2: Switching time test circuit

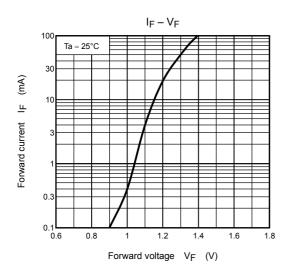


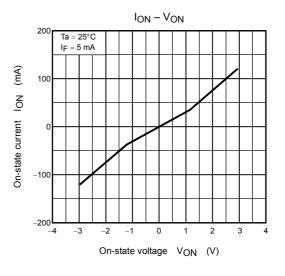


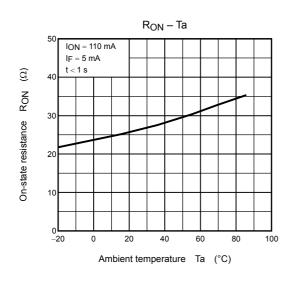
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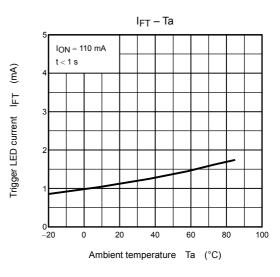




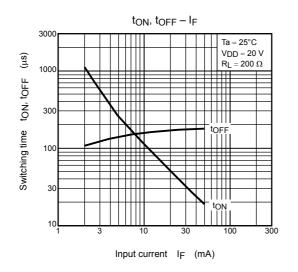


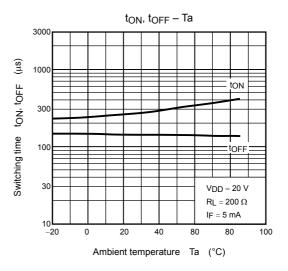


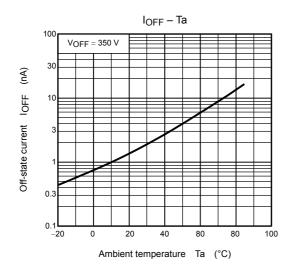




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